Continued from preceding page.

Parameter	Symbol	Conditions	Ratings	Unit
Collector Dissipation	PC		500	mW
		When mounted on ceramic substrate (250mm <sup>2</sup> ×0.8mm)	1.3	W
Junction Temperature	Тј		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

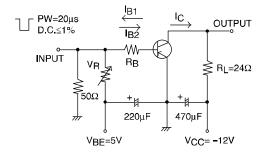
### **Electrical Characteristics** at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			1.1
			min	typ	max	Unit
Collector Cutoff Current	ICBO	V <sub>CB</sub> =-20V, I <sub>E</sub> =0A			-0.1	μΑ
Emitter Cutoff Current	IEBO	V <sub>EB</sub> =-4V, I <sub>C</sub> =0A			-0.1	μΑ
DC Current Gain	hFE1	V <sub>CE</sub> =-2V, I <sub>C</sub> =-100mA	140*		400*	
	hFE2	V <sub>CE</sub> =-2V, I <sub>C</sub> =-1.5A	65			
Gain-Bandwidth Product	fT	V <sub>CE</sub> =-10V, I <sub>C</sub> =-50mA		150		MHz
Output Capacitance	Cob	V <sub>CB</sub> =-10V, f=1MHz		32		pF
Collector to Emitter Saturation Voltage	V <sub>CE</sub> (sat)	I <sub>C</sub> =-1.5A, I <sub>B</sub> =-75mA		-0.35	-0.6	V
Base to Emitter Saturation Voltage	V <sub>BE</sub> (sat)	I <sub>C</sub> =-1.5A, I <sub>B</sub> =-75mA		-0.85	-1.2	V
Collector to Base Breakdown Voltage	V(BR)CBO	I <sub>C</sub> =-10μA, I <sub>E</sub> =0A				V
Collector to Emitter Breakdown Voltage	V(BR)CEO	I <sub>C</sub> =-1mA, R <sub>BE</sub> =∞	-25			V
Emitter to Base Breakdown Voltage	V(BR)EBO	I <sub>E</sub> =-10μA, I <sub>C</sub> =0A	-6			V
Turn-ON Time	ton			60		ns
Storage Time	t <sub>stg</sub>	See specified Test Circuit		350		ns
Fall Time	tf			25		ns

<sup>\*:</sup> The 2SB1121 is classified by 100mA hFE as follows:

Rank	S	T
hFE	140 to 280	200 to 400

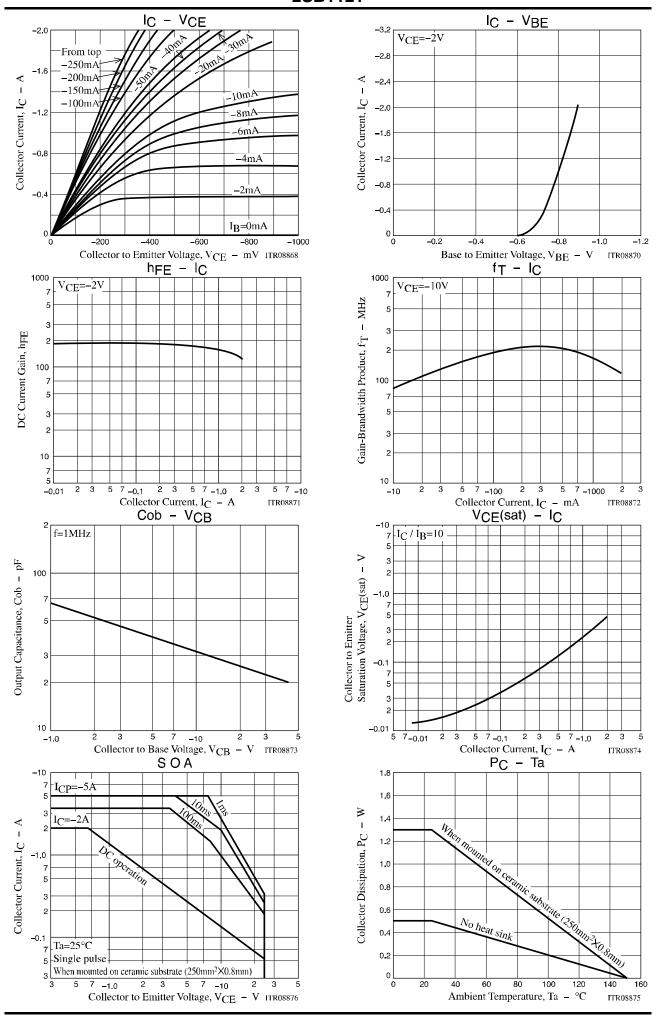
# **Switching Time Test Circuit**



 $I_{C}=20I_{B1}=-20I_{B2}=-0.5A$ 

## **Ordering Information**

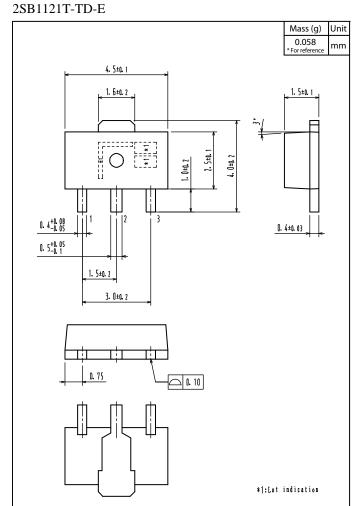
Device	Package	Shipping	Memo
2SB1121S-TD-E 2SB1121T-TD-E	PCP	1,000pcs./reel	Pb-Free

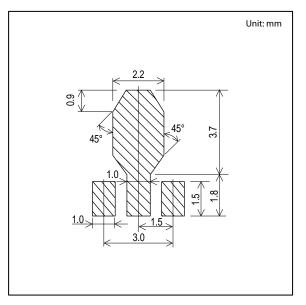


### **Outline Drawing**

2SB1121S-TD-E

### **Land Pattern Example**





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